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A Novel High Temperature Sensor Architecture for Harsh Environments

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I. Abstract

To improve the stability and functionality of the reactor monitoring the exact condition due to high temperature, neutron irradiation, corrosive condition to is very important.

Methods to monitor temperature:

- Thermocouples: unreliable after short time exposer to radiation.
- Melt wires techniques: lower resolution.
- Optical waveguide sensor: high accurate measurement result, multi-use.



Fig. 1. Melt wire techniques [1].

II. Motivation and Method

❖ **Objective:** Design small size, highly accurate, real-time and reversible temperature sensor at 1550 nm wavelength.

❖ Hybrid plasmonic waveguide:

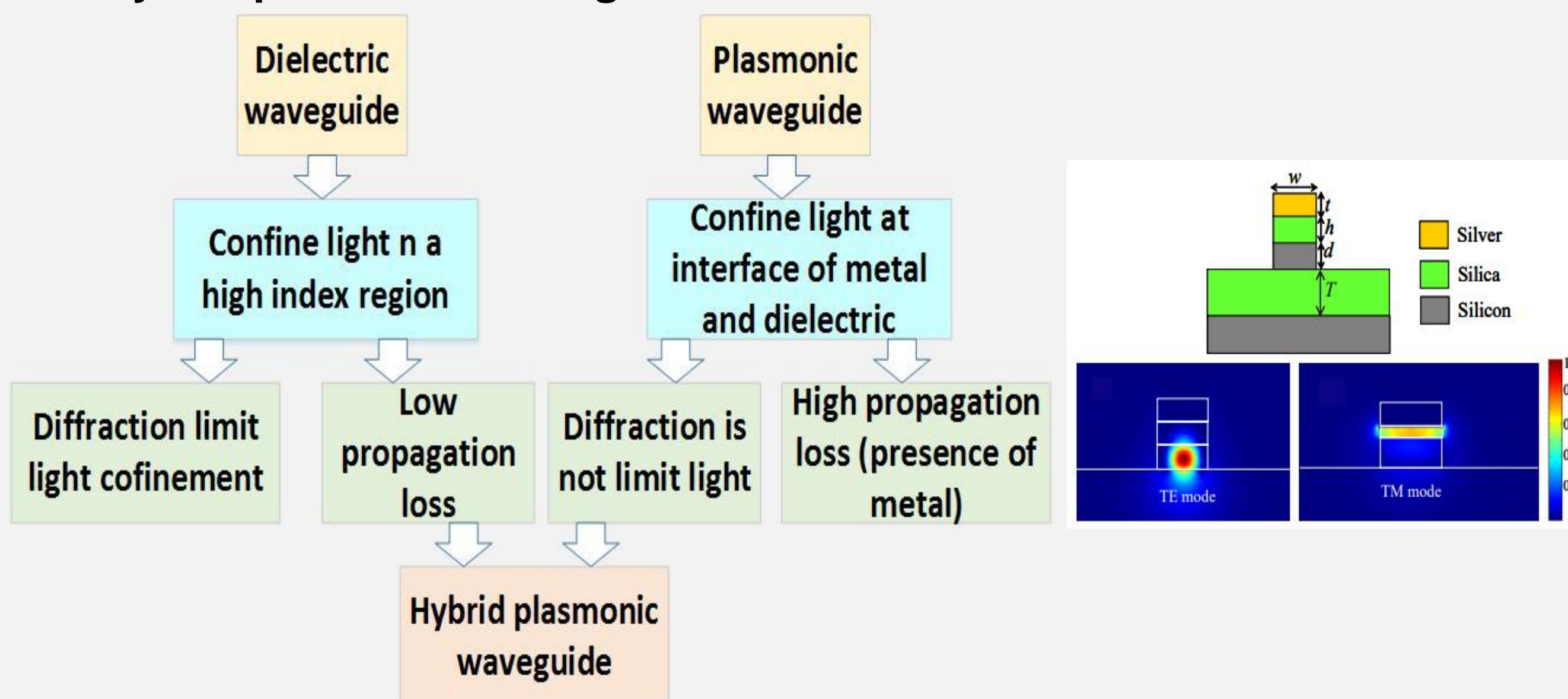


Fig. 2. Hybrid plasmonic waveguide properties.

Fig. 3. Basic structure of Hybrid plasmonic waveguide.

❖ Chalcogenide glass (ChG):

A glass containing one or more chalcogens (sulfur, selenium and tellurium)

- Temperature sensitive:
- Switch between an amorphous (dielectric) and a crystalline (metal) state by controlling heating and annealing (cooling) [2].

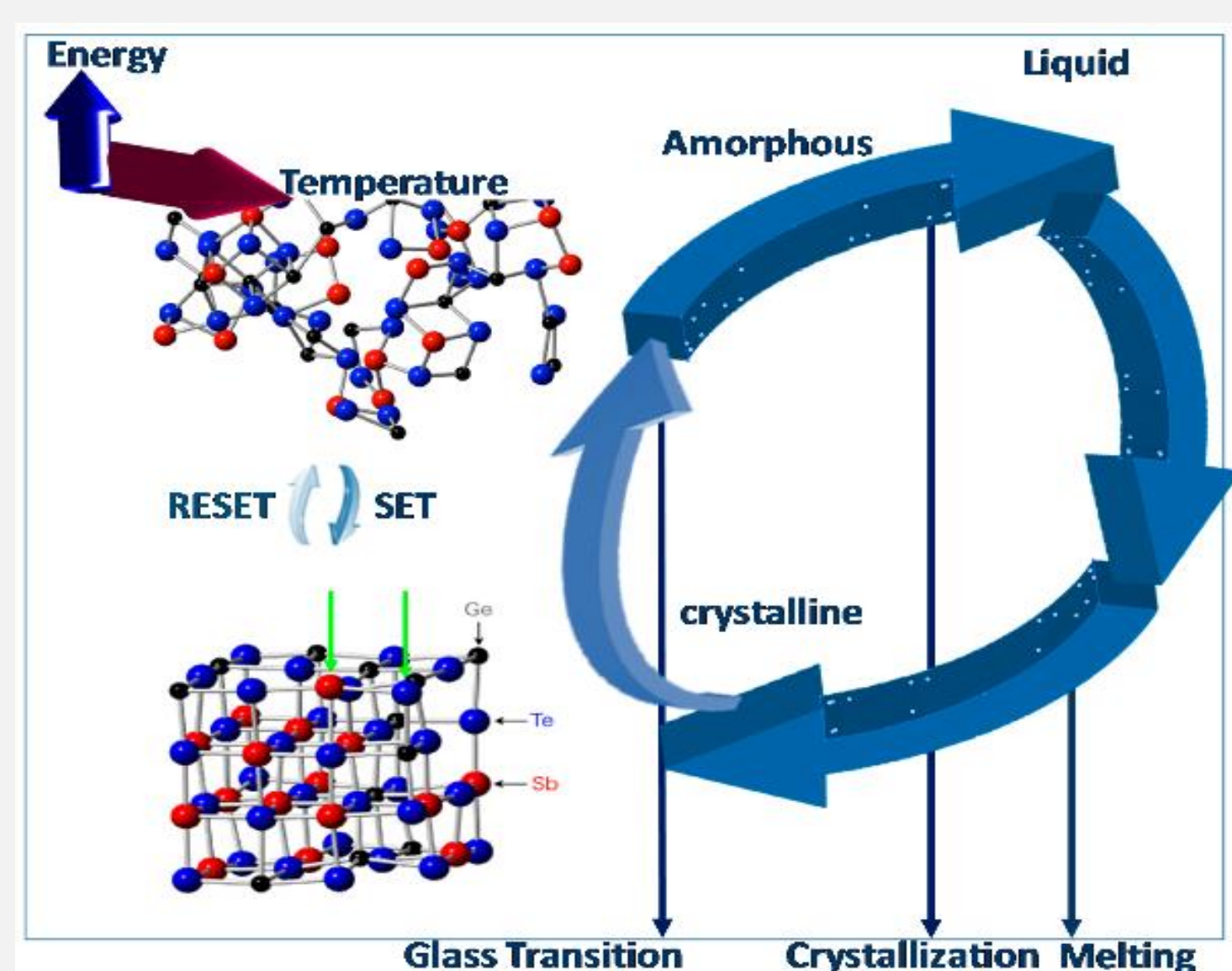


Fig. 4. Phase transition of ChG.

III. Design and Results

- Combining phase change properties of chalcogenide glasses and compactness of radiation hard Si waveguide.
- Place ChG placed on silicon [3].

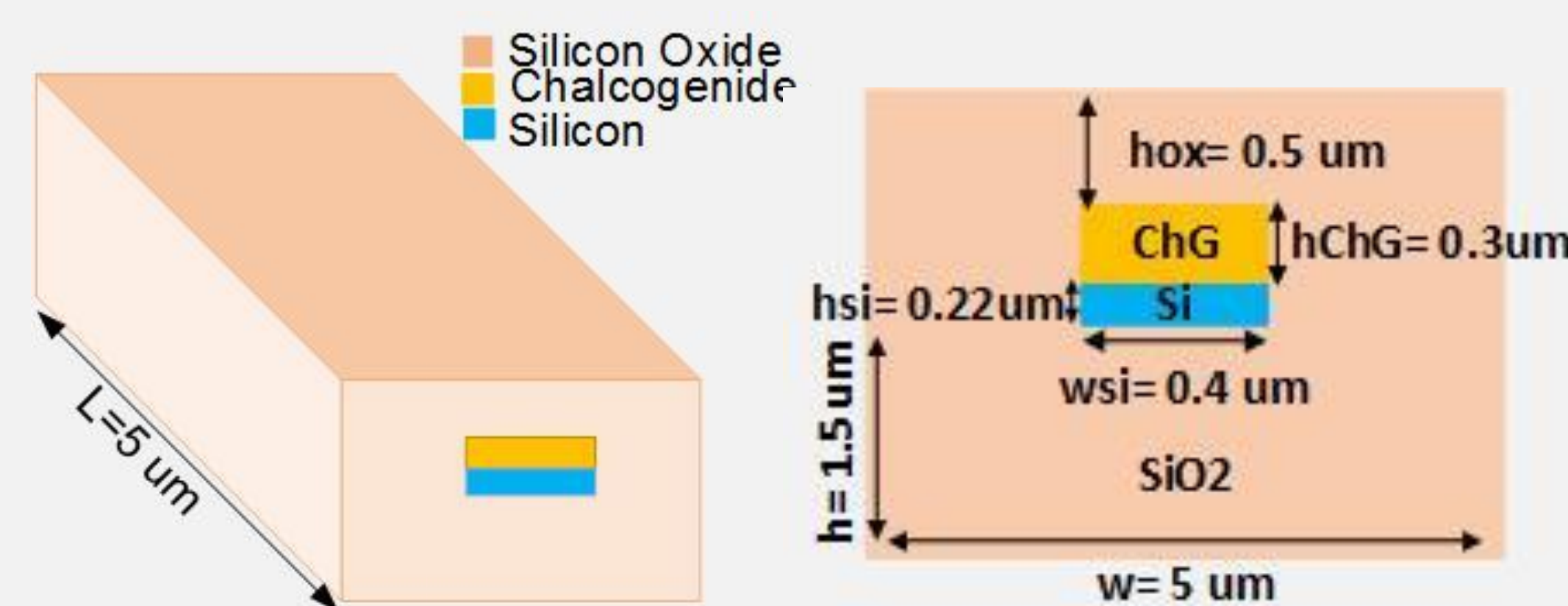


Fig. 5. Proposed hybrid plasmonic waveguide

❖ Amorphous phase

- Fundamental TE and TM modes confinement of propagating light is in Si.
- Fundamental TE and TM propagate along with waveguide with minimum loss and low absorption in near infrared.

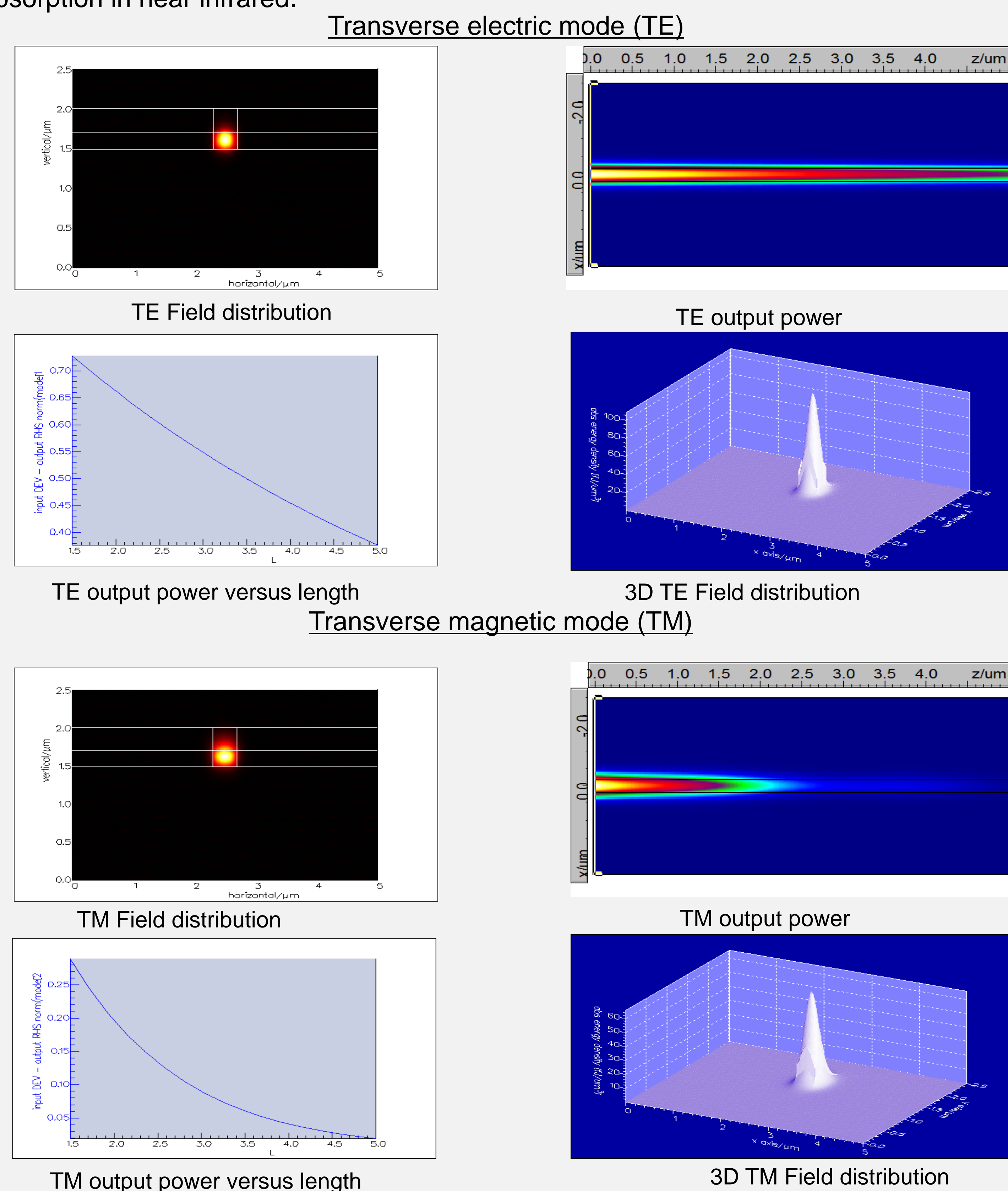


Fig. 6. TE and TM modes in amorphous phase.

IV. Results Cont'd

- Plasmonic mode appears at interface between silicon and metal.
- Electrical field of the excited SP wave decays exponentially at Both sides of the interface.
- Plasmonic mode in crystalline phase have higher propagation losses ($\sim 1dB/\mu m$) than amorphous phase.

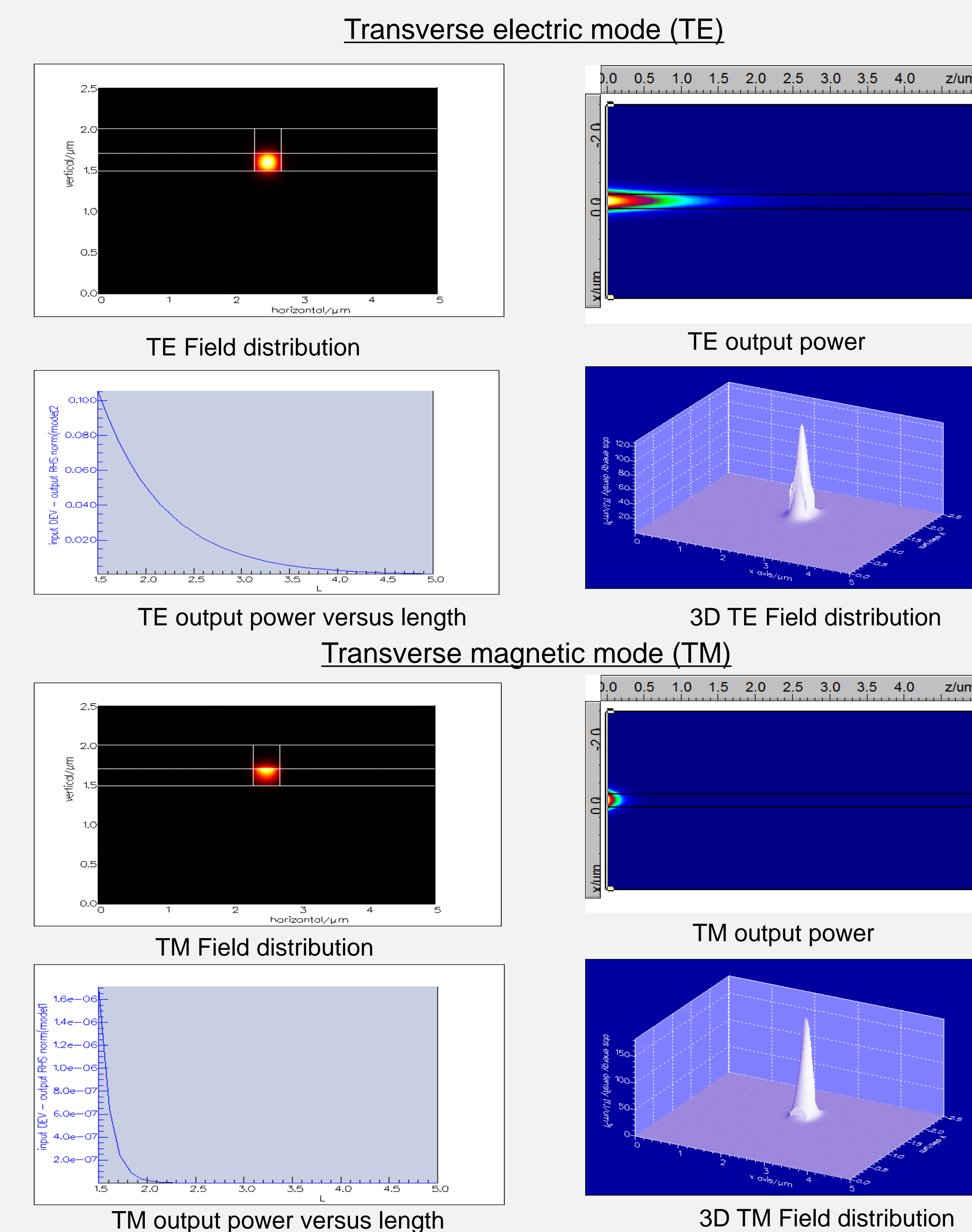


Fig. 7. TE and TM modes in crystalline phase.

V. Conclusion

- Transforming the phase of ChG in specific crystallization temperature changes the confinement and propagation loss of the waveguide.
- Crystalline to amorphous phase change of ChG facilitates multiple time use of the sensors.
- Different crystallization temperature based on composition of active ChG generates a temperature sensors in desire applications.

ACKNOWLEDGEMENTS

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